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# **Product/Process Change Notice**

(Initial and date all changes/No pencil or whiteout/Cross out all errors.)

PCN #: 110607-154	Ме	Means of Distinguishing Change :					
Part #: FM28V020		Product Mark Date Code	All parts and all date codes.				
Date Issued: 6/07/11		Other Other					
Date Effective: 6/07/1	1						
Purpose of Change:	Recent evaluation has show undershoot/overshoot near t at high $V_{DD}$ levels, fast cycle	n the part to be he specified lir e times, and at	e sensitive to output loading and I/O nits. This condition is more pronounced low temperatures (near -40C).				
Assembly Test Manufacturing Data Sheet Product Mark Other	Although problems have no consider the margin to be in (see page 2 for spec compar The PCB Layout Recommen mitigating any potential pro-	t been observed sufficient. The ison) until sucl ndations (see d blems.	d at the data sheet conditions, we data sheet is therefore being changed n time as the design can be improved. atasheet pg. 6) are effective in				

## **Quality Assurance Summary:**

Part numbers affected:

FM28V020-G FM28V020-GTR

Contact: pcnadmin@ramtron.com

## **AC Timing Parameters** ( $T_A = -40^{\circ}$ C to $+85^{\circ}$ C, $C_L = 30$ pF, $V_{DD} = 2.0$ V to 3.6V unless otherwise specified)

		Previous Spec (Data sheet Rev 2.0 and prior)			New (Data Rev	Spec sheet 2.1)		
Symbol	Parameter	Min	Max		Min	Max	Units	Notes

### READ CYCLE PARAMETERS

t <sub>RC</sub>	Read Cycle Time	90	-	140	-	ns	
t <sub>CE</sub>	Chip Enable Access Time	-	60	-	70	ns	
t <sub>AA</sub>	Address Access Time	-	90	-	140	ns	
t <sub>AAP</sub>	Page Mode Address Access Time	-	30	-	60	ns	
t <sub>CA</sub>	Chip Enable Active Time	60	-	70	-	ns	
t <sub>PC</sub>	Precharge Time	30	-	70	-	ns	
t <sub>AH</sub>	Address Hold Time (/CE-controlled)	60	-	70	-	ns	

#### WRITE CYCLE PARAMETERS

t <sub>WC</sub>	Write Cycle Time	90	-	140	-	ns	
t <sub>CA</sub>	Chip Enable Active Time	60	-	70	-	ns	
t <sub>CW</sub>	Chip Enable to Write Enable High	60	-	70	-	ns	
t <sub>PC</sub>	Precharge Time	30	-	70	-	ns	
t <sub>AH</sub>	Address Hold Time (/CE-controlled)	60	-	70	-	ns	
t <sub>AWH</sub>	A(14:3) Change to Write Enable High	90	-	140	-	ns	